The 3B20D Processor & DMERT Operating System:

3B20D Packaging and Technology

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The 3B20D Processor is built using a broad range of complex and high-performance integrated circuits. These integrated circuit devices are packaged and interconnected utilizing Bellpac™ packaging system technology. Used throughout the processor are high-density multilayer printed wiring boards with high pin-out connectors. The elements of the technology were combined using computer-aided design tools to assure optimized system thermal and electrical performance.

I. INTRODUCTION

The cost, performance, and schedule objectives of the 3B20D Processor and the overall complexity of the design required:

- A full spectrum of circuit integration
- Common integrated circuit specifications
- A broad range of semiconductor memory devices
- A standard hardware packaging technology
- Quick turnaround prototype circuit packs
- High interconnection capability at the circuit pack level
- A hierarchy computer aided design (CAD) process
- Comprehensive design audits in the CAD process.

The use of *Bellpac** packaging system technology provides a dense, high performance packaging system.¹ This includes a substantial increase in the number of devices allowed per circuit pack and the number of contacts per pack over previous technologies. The use of *Bellpac* packaging technology also allowed a low system cost since the

^{*} Bellpac is a trademark of Western Electric.

hardware is Bell System standard and manufactured in high volume. Complex integrated circuits from a variety of vendors were employed throughout the 3B20D Processor. A wide variety of integrated circuits and comprehensive specifications were used to optimize processor performance, cost, and reliability. *Bellpac* packaging technology and the integrated circuits were coupled together through a sophisticated CAD system. The CAD system is comprised of design, analysis, simulation, and audit tools at device, circuit pack, unit, and frame levels.

II. INTEGRATED CIRCUITS AND APPARATUS PERFORMANCE

2.1 General device requirements

The integrated circuit device family used in the 3B20D Processor consists of approximately 280 codes of TTL (Transistor-Transistor Logic) compatible SSI (Small-Scale Integration), MSI (Medium-Scale Integration), and LSI (Large-Scale Integration) devices. These codes were selected to optimize the cost and performance of the wide range of processor functions included in the central control, memory, and peripherals. Device performance range varies greatly from the highspeed, speed-selected, bipolar Schottky TTL parts in the central control to relatively slow metal oxide semiconductor microprocessor peripherals in the I/O area. The scale of integration varies from SSI devices driving heavily loaded buses to VLSI (Very Large-Scale Integration) memory and microprocessor devices. Whenever possible, where system performance and/or cost was not jeopardized, the same parts were used in several different areas of the design to minimize the number of unique integrated circuits. Where the same device could be used for multiple functions, the device specification was written to cover the extreme needs of all applications.

To assure that all of these devices would interface with each other, common device specifications were established. The temperature range for the devices was specified as 0–95°C to accommodate central office equipment requirements and to keep cooling costs low. Supply voltage limits were established at 5 volts \pm 10 percent to minimize power generation and distribution costs. The interface levels were established based on TTL standards (i.e. $\mathrm{Vol} \leq 0.4\,\mathrm{volt}$, $\mathrm{Voh} \geq 3.4\,\mathrm{volts}$) consistent with the temperature and supply standards described above. Other common standards included dual in-line package (DIP) dimensions and lead finish specifications to ensure manufacturability and reliability.

As the project progressed through its phases, the reliability requirements for devices varied. For the initial system models, high-reliability devices with good electrical performance were essential to minimize

interference with software/hardware integration. This was particularly true with devices on prototype wire-wrap hardware, which generate substantially more noise and crosstalk than the production multilayer designs. Since much of the prototype hardware was built before final device specifications could be negotiated with vendors, high-quality military grade parts were procured wherever possible and special screens were imposed where high-reliability parts could not otherwise be obtained. For production units, reliability requirements were established based on system availability objectives.² For most of the codes this worked out to a 100 FIT* objective per device. This objective was translated into specific packaging, burn-in, screens, and life-testing requirements in the device specifications.

Special devices required creation of a number of expanded specifications. For example, to simplify circuit pack testing or to provide a low-cost method for changing information contained in PROMs, reliable socketing was required which, in turn, required special gold lead finishes on the devices. A small number of other devices, for cost or availability reasons, were specified at reduced temperature and/or supply voltage ranges.

2.2 Small-scale and medium-scale integration devices

There are about 160 codes of devices that can be classified as having small-scale integration (SSI) or medium-scale integration (MSI). These consist of two basic device groups: LSTTL and STTL. The LSTTL gates are typically characterized as having 10 ns, 2 mW parts, and the STTL gates as having 5 ns, 20 mW parts. Both families meet industry standards and are widely available. The identical functions are generally available in both families. Due to the much lower power of the LSTTL devices, they were preferred except where speed was critical. To maximize the use of the LSTTL devices a special output current drive requirement was specified that effectively doubled their capacitive drive performance under worst-case conditions. Since the STTL devices were used in the speed-critical paths, their performance had a major part in establishing system performance. On a subset of these devices, special speed screens at high-capacitive loads were specified. The increased cost of these screens on these few device codes was minimal at the system level, but the system performance gain was substantial.

In addition to the standard logic devices in the SSI and MSI category, there were a variety of special devices such as delay lines (10 codes) and oscillators (10 codes). These devices generally had STTL and LSTTL interfaces to the other devices.

^{*} FIT is defined as one failure in 109 operating hours.

2.3 Memory devices

The semiconductor memory device requirements for the various processor functions were broad. They included dynamic RAMs, static RAMs, PROMs, Electrically alterable PROM (EPROM), and First In First Out (FIFO) memories in a variety of functional organizations and speed ranges.

The dynamic RAMs used in the 3B20D for main storage are 64K-bit chips manufactured by Western Electric. They are organized 64K words by 1 bit and have an internal redundancy that was used to increase yield.

Static RAMs are used in a variety of applications including cache, microstore, memory management, and the address/data storage for the microprocessor-based circuits. The first three applications require high-speed memory, while the address/data storage requires high density at moderate speed (16K bits at 200 ns). There are 10 codes of static RAM in the 3B2OD Processor.

The programmable memories (PROM, EPROM) are used in the microstore and as program memory in microprocessor-based designs. In addition, smaller PROMs have been used in sequencer designs. In many designs these parts are used interchangeably with static RAMs. Again organization, speed, and power requirements are varied and result in 17 codes of programmable memories. The FIFO memories used in the 3B20D Processor are moderate-speed devices, primarily used for data buffering.

2.4 Large-scale integration logic

Because of the low cost per gate available with LSI logic its use was chosen wherever available parts could meet performance and functional requirements. The parts that were chosen provide large general-purpose functional blocks, such as microprocessors and associated peripherals, protocol controllers, dynamic RAM controllers, etc. Because of the relatively long development time and high development cost for LSI parts, new custom LSI designs were not undertaken during the initial 3B20D development stages. Cost reduction and new feature designs completed after the initial design phase have tended to use LSI gate arrays. There are a total of 30 catalog LSI codes and 16 LSI gate array codes in the 3B20D.

2.5 Circuit packs

The smallest replaceable module of the 3B20D is the circuit pack. Each pack consists of a collection of integrated circuits, in dual in-line packages, interconnected on circuit boards using the *Bellpac* packaging system (see Fig. 1). Typical circuit boards use a multilayer printed wiring board structure, which consists of six layers with plated through

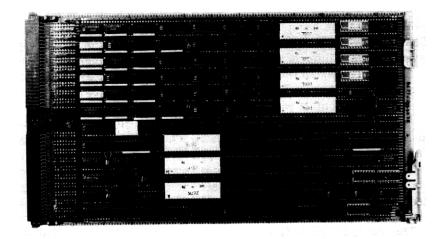


Fig. 1-The 3B20D Processor circuit pack.

holes to interconnect the layers. The structure of the printed circuit board is as follows: a component surface/signal layer, a signal layer, a power layer, a ground layer, a signal layer, and a wiring surface/signal layer. Board design used a standardized 0.100-inch grid to facilitate computer aided design and also to permit automated assembly and test. Protection for surface-layer printed wiring is provided by a cover coat that is applied prior to component assembly. The circuit pack multilayer board is normally 7.67 by 13.375 inches (although a few 7.67 x 9.375-inch boards are also used). All boards are 0.062 inch thick.

The circuit pack designs use either a 200-contact or 300-contact connector to interconnect the pack to a unit backplane. The connectors consist of a matrix of contacts contained in a plastic housing soldered to the edge of the printed circuit board. These contacts are bifurcated and selectively gold plated to provide a low-resistance, low-cost connection that will perform well over a 40-year design life. The circuit pack connector mates with a matrix of 0.025-inch-square pins mounted in the backplane on a 0.125-inch grid. The mating of the circuit pack contact with the backplane pin results in a loading of the bifurcated contact with a minimum normal contact force of 100 grams at the end of a 40-year life. The backplane pin is also selectively gold plated to provide a high-reliability, low-cost contact.

2.6 Frame unit

The next level of circuit packaging is the frame unit. Circuit packs mount into a frame unit that consists of a backplane printed wiring board with pins and apparatus mountings to support the packs. The backplane board is approximately 8.00 by 22.55 inches in size and

typically interconnects 21 circuit packs. Three apparatus mountings mount across the backplane to guide and support the circuit packs. The structure of the printed wiring backplane consists of six circuit layers that are interconnected with plated through holes. Pins are staked into the plated through holes on a 0.125-inch grid to match the circuit pack connector. These pins have low assembly cost and make highly reliable contact with the circuit boards.

The apparatus mounting provides circuit pack support and alignment with the backplane pins (Fig. 2). The apparatus mounting is designed to provide minimum impedance to air flow moving vertically through the unit. A designation strip is located at the top front of the mounting identifying the appropriate circuit packs. Matching the designation strip with the plastic faceplate of each circuit pack ensures proper installation.

The pins in the backplane extend on both sides of the printed wiring board. On the side of the backplane away from the circuit packs, additional connections between circuit packs can be made by wire, automatically wrapped to the pins. The majority of circuit pack

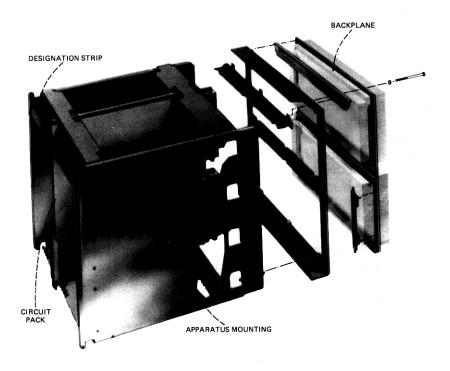


Fig. 2—The 3B20D Processor frame unit.

interconnections are made by signal paths within the backplane multilayer board; wires are used for changes or for connections that could not be routed in the printed circuit board. Also this side of the backplane is used for interconnecting different frame units or frames via connectorized cables. Many different connectors are used varying in size from 6 contacts to 24 contacts. This cable connector family supports both discrete wire (or switchboard) cable as well as multiconductor tape cable. The cable connectors are guided and retained on the backplane with special cable connector apparatus mountings that are attached to the backplane.

III. 3B20D UNIT PHYSICAL DESIGNS

3.1 Control unit frame

The 3B20D control unit frame is the core of the processor. Its modular equipment design permits the equipage of optional hardware features suitable to support a wide range of applications. The control unit frame in its maximum configuration contains the following units: central control, main store module 0 and 1, direct memory access input/output, cooling, and power. Figure 3 shows a maximally configured frame and denotes those units not required in a basic 3B20D Processor.

The 3B20D Processor frame units are mounted in a 7-foot-high, 24inch-deep, 2-foot 2-inch-wide framework as shown in Fig. 3. Optional units and/or circuit packs are simply omitted where host system requirements do not require them. Subsequent paragraphs provide a description of the control unit frame units and their functions.

3.1.1 Central control unit

The central control unit is 10 inches high by 2 feet 2 inches wide. It contains the following required circuit functions:

- (i) Central processing unit
- (ii) Microstore
- (iii) Main store update
- (iv) Maintenance channel.

It has circuit pack positions allocated for the following optional features:

- (i) Two input/output channel boards
- (ii) Growth microstore
- (iii) Cache
- (iv) Utility circuit.

Also a circuit pack position has been reserved for the connection of a test set. The unit includes a fuse block, extending the full width of the unit, which provides individual fusing for each pack.³

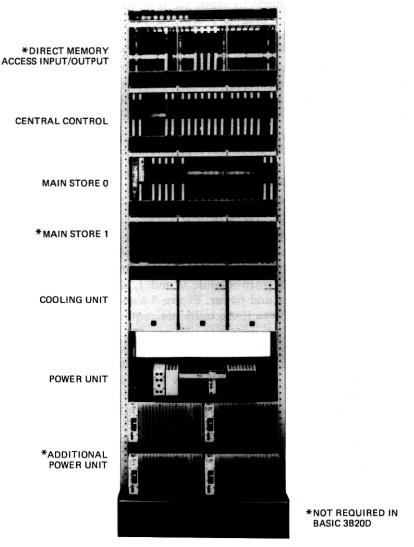


Fig. 3—The 3B20D Processor central control frame.

3.1.2 Main store unit

The main store units are each 10 inches high by 2 feet 2 inches wide and may be equipped with a maximum of 16 megabytes of memory. The unit is minimally equipped with store controller packs and with one array pack. Additional main store array packs can be added one at a time to form a maximum complement of 16 array packs per module. When a unit is using 512K-byte arrays, two main store units

may be used per frame to provide up to 16 megabytes of memory; when 1024K-byte arrays are used, only one memory unit is required for the maximum addressable 16 megabytes of memory.⁴

3.1.3 Direct memory access unit

The Direct Memory Access (DMA) unit is 10 inches high by 2 feet 2 inches wide and is used for expansion of I/O channel requirements beyond the two positions provided in the central control unit. It also houses the DMA controllers and their associated I/O channels.³ A total of five positions are available for I/O expansion. I/O channels that can be equipped in these positions include the dual-serial channel, serial channel, and applications channel interface packs. There is room in the unit for two DMA controllers, although normally only one is equipped. Each DMA controller is equipped with a dual-serial channel with the option to add up to three additional dual-serial channel packs.

3.1.4 Cooling unit

The cooling unit is 8 inches high by 2 feet 2 inches wide and provides forced air cooling to keep device temperatures within specifications. The cooling unit is divided into three replaceable fan module assemblies, each with a fan and filter.

3.1.5 Frame power system

Power for the control frame is provided by the power unit located at the base of the frame. The power unit includes bulk power converters, a reference supply, and a power distribution/fusing system. Two to four -48 to +5 volts dc power converters are tied in parallel to provide power to all frame units via a frame and fuse panel bus bar system. The +12 volt power required by the devices used on the 512K-byte store arrays is supplied by a -48 to +12 volt dc converter located in the power unit. The power unit is also equipped with input fuses for each of the converters and for the reference supply. The power switch for the frame is implemented as a common design circuit pack which provides control and power sequencing for the frame and is located in the main store unit.

3.2 Peripheral control frame

The Peripheral Control Frame (PCF) houses those units which provide the interface communications between the 3B20D Processor and its periphery. This frame in its maximum configuration is equipped with an Input/Output Processor (IOP) basic unit, IOP growth unit, a Disk File Controller (DFC) unit, and a cooling unit. A port switch unit is also provided in one of the peripheral control frames. The frame is

a framework 7 feet high, 24 inches deep by 2 feet 2 inches wide. The following paragraphs describe the various units within this frame.

3.2.1 Input/output processor basic unit

The IOP basic unit is 16 inches high by 2 feet 2 inches wide and has a self-contained power system. This unit is subdivided into a processor section and two peripheral controller (PC) communities; each of the latter can be equipped with up to four PC circuit packs. The power switch circuit pack provides power control and sequencing functions to this unit and to the growth unit if present. DC to DC converters and a fuse system similar to the one used in the control frame complete the power system.⁵

3.2.2 Input/output processor growth unit

The IOP growth unit can be added to the basic unit to provide additional PC communities. It is 10 inches high by 2 feet 2 inches wide. This unit provides two communities of up to four PCs each to meet additional host system peripheral requirements. The self-contained power system for this unit is controlled by the power switch in the IOP basic unit.⁵

3.2.3 Disk file control unit

The DFC unit is 16 inches high by 2 feet 2 inches wide and includes a self-contained power system. The DFC is used to interface the 3B20D control unit with the disk memory system. Control and data communications are provided for the moving head disk drives.

3.2.4 Cooling unit

The cooling unit used in the PCF is the same design as used in the control unit frame (see Section 3.1). This unit is located below the IOP basic or growth unit as appropriate to provide forced air cooling.

3.2.5 Port switch unit

The port switch unit is 4 inches high by 2 feet 2 inches. This self-powered unit provides one or two communities of up to three port switches each and also has positions for up to five scan and signal distribution interface circuits. One community is required for the port switching of the maintenance terminals.

IV. ELECTRICAL AND PHYSICAL DESIGN PROCESS

The electrical and physical design of the 3B20D Processor was based heavily on the application of a computer aided design process and the use of design standards and audits. Design standards were established and used to control the design process and to assure commonality among separate design activities. The design audits were used to provide a predicted measure of system performance based on a given design and thus allowed feedback for making design changes to maximize system performance.

4.1 Circuit pack, unit, and frame design

The fundamental hardware building blocks (circuit packs, units and frames) were designed and tied together with the assistance of a CAD system. After the initial paper design, a circuit pack design file was created in the CAD system that contained all connectivity information. The design file represents the official record for the circuit. Circuit board manufacturing information, schematic drawings, design audits, and system connectivity can be created from these files. As the design progressed and various information was created, such as board routing, schematic representation, etc., it was added to the file. This circuit pack design file was also used to generate the software simulation files which were used to functionally verify the design and generate circuit pack test information.⁷

Fundamental to the CAD system were the design standards used throughout the 3B20D Processor. The design standards include a project library with integrated circuit and circuit board topology information, fixed power and ground pinouts for circuit packs, and common hardware definitions. The standards also provided specific rules for electrical design (fanout, crosstalk, etc.) that could be audited by the CAD system.

The interconnection of the different circuit packs within a unit was captured in a unit design file in the CAD system. These files contained all connectivity information and, like the circuit pack files, provided the basis for developing and storing detailed wiring information for the unit backplanes.

Frame drawings were a composite of design information from the unit files, with connectivity between the units added. Also included in the frame drawings was power distribution information.

4.2 Designing for system crosstalk and noise margin

The rapid switching transitions in TTL logic made noise and crosstalk performance a critical design criterion. For the system to operate successfully, noise had to be kept well below the switching thresholds of the integrated circuit devices used over a wide range of device temperature, supply voltage, and packaging variations. The large number of signal nets and the difficulty of tracking down subtle noise problems in a system as complex as the 3B20D dictated a set of design rules based on worst-case conditions. Comprehensive audits were made to assure compliance with these rules.

Two major noise audits were provided for the 3B20D. The first was a crosstalk audit (parallelism audit) that searched the circuit pack and backplane routing files to identify for each net all signal nets immediately adjacent and parallel to the net of interest and sum the exposures. Through theoretical calculations and experimental results a maximum safe exposure limit was established for each device type. All nets exceeding this crosstalk exposure limit were referred for further analysis to the circuit designer. The designer's analysis would determine whether rerouting was required to assure that system performance was not adversely affected. The second major noise audit was for current shuttling. Analysis for this audit is a complex function of the device types and detailed routing information. Using a device parameter library and the circuit pack routing files, the current shuttling audit generates a list of all nets with potential noise problems. These nets were then reviewed by the circuit designer.

A fanout audit also was provided. This audit is based on detailed device drive and loading information in the device library and on the circuit pack and unit connectivity files. Violations of the fanout rules can result in reduced noise margins, or in extreme cases, malfunction of the logic.

4.3 Timing analysis

Timing analysis consisted of computing the minimum and maximum delay for each device in a path of interest under actual load conditions. The delay consists of an intrinsic component through the device itself and an interconnection component that depends on the wiring parameters, fanout, and the output drive capabilities. CAD programs and libraries were developed to extract the interconnection data to compute the device and path delays.

4.4 Thermal analysis

Computer aided tools also were used for thermal analysis. In particular they were used to predict device temperatures on certain heat-sensitive devices in the frame environment. The tools used an experimentally determined heat transfer coefficient and integrated circuit power dissipations to calculate device temperatures. In addition to confirming the adequacies of the design, these tools were used to specify temperatures for selected heat sensitive devices where device cost, performance, and temperature were important trade-offs.

V. FLEXIBLE FLOOR PLAN

Because the 3B20D Processor was designed as a cost-effective processor for a wide range of Bell System applications, it usually will be installed as a group of frames within the host system environment; in

other cases, such as retrofit environments, the processor frames may have to fit into the space available. The 3B20D has been designed to support both of these situations. From an environmental standpoint, no special air-conditioning diffusers are required for the 3B20D equipment. However, sufficient cooling and ventilation must be provided so that the aisle air temperature does not exceed 37°C on a long term basis or 49°C for a short term.

The recommended typical floor plan for the 3B20D is shown in Fig. 4. This plan depicts a basic processor with its most likely growth patterns and satisfies most system applications. Moving head disk cables and associated duct work have been designed to support the typical plan. Other floor plans are permitted providing cable length restrictions are observed. These cases may require special cables and/or duct work which would have to be engineered as part of the host system.

VI. TECHNOLOGY PERFORMANCE

6.1 Rapid development

To assure a rapid development of the 3B20D Processor, standardized hardware components and special prototype hardware were used. The basic *Bellpac* packaging system hardware building blocks were used wherever possible to reduce availability intervals. Quick-turnaround wire-wrap boards were used for prototype circuit packs and backplanes. The use of a CAD system allowed the transition from wire-wrap to multilayer design to be a minimal design effort. The net result



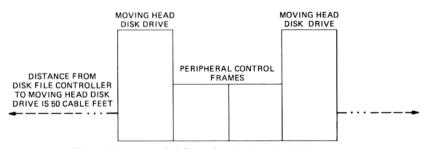


Fig. 4-Recommended floor plan for the 3B20D Processor.

of the use of off-the-shelf hardware, computer aided designs, and wire wrap models was that the objective project development schedule was achieved.

6.2 System electrical performance

The electrical performance of a system is best measured by the successful achievement of system performance objectives and the lack of timing and noise problems. Using the technology system described, all 3B20D performance objectives have been met. Further, despite the high degree of complexity, few noise and timing problems were encountered in the actual hardware. This successful result was achieved by the coordinated and comprehensive set of device and packaging specifications and design aids and audits.

6.3 Thermal performance

The 3B20D Processor is designed to operate in a normal environment of less than 37°C and at a maximum elevation of 6000 feet above sea level. In the event of a building cooling failure, the processor will remain operable in air temperatures of up to 49°C. During these building cooling failures, the circuit board temperatures do not exceed the design goal of 95°C in the control frame and DFC. In the IOP units there are a number of critical LSI devices, which are kept below 70°C to maintain good timing margins. All peripheral equipment (disk drives, tape drives, printers, and terminals) is tested by the respective vendor for operation up to 49°C.

Final thermal acceptability of each 3B20D system to be shipped is verified in a factory heat test where each processor system, with peripherals, is heated to 49°C for a 6-hour functional test.

VII. ACKNOWLEDGMENT

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